

MOSFET Guide

Objective

To measure and understand the current-vs-voltage (I - V) operating curves of the MOSFET.

MOSFET I-V Characteristics

A metal-oxide-semiconductor field-effect transistor (MOSFET) is a three-terminal device that can be used as a switch (e.g. in digital circuits) or as an amplifier (e.g. in analog circuits). The three terminals are referred to as the **Source**, **Gate**, and **Drain** terminals. The MOSFET also has a **Body** terminal, which is usually tied to the source terminal (so that $V_{BS} = 0$ volts) in discrete transistors. **Current flow between the source and drain terminals is controlled by the voltage V_{GS} applied between the gate and source terminals.** If the gate-to-source voltage V_{GS} is less than the threshold voltage value V_T (e.g. ~ 2 Volts, for the transistors which you will be using in this lab), no current can flow between the source and the drain – i.e. the transistor is OFF; if $V_{GS} > V_T$, then current can flow between the source and the drain – i.e. the transistor is ON. The circuit symbol for an n-channel enhancement-mode ($V_T > 0$ Volts) MOSFET is shown in Figure 1, along with the terminal current reference directions.

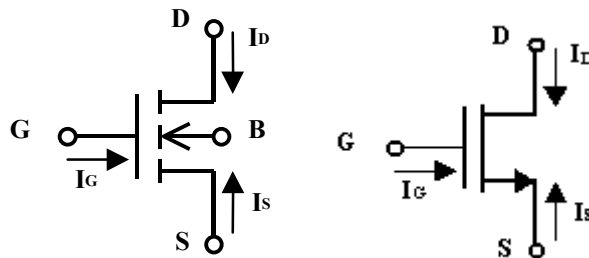


Figure 1 Circuit symbol for n-channel enhancement MOSFET

Note that each terminal current is defined to be positive flowing into the terminal. In the physical structure of the MOSFET, the gate terminal is electrically insulated from the source, body and drain terminals, so that no DC current can flow into the gate terminal:

$$I_G = 0$$

In addition, if the transistor is operated properly, no DC current should flow between the body terminal and the source or drain terminals:

$$I_B = 0$$

From Kirchhoff's Current Law, we know that the sum of all the terminal currents flowing into the MOSFET must be zero:

$$I_G + I_D + I_B + I_S = 0$$

Substituting, we obtain

$$I_S = -I_D$$

Thus, all of the current that flows into the drain terminal flows out of the source terminal.

In the ON state, the current I_{DS} flowing from the drain to the source will depend on the potential difference V_{DS} between the drain and the source: I_{DS} increases with increasing drain-to-source voltage V_{DS} as long as the drain voltage is at least V_T below the gate voltage, *i.e.* as long as $V_{GS} - V_T > V_{DS}$. When V_{DS} increases above $V_{GS} - V_T$, I_{DS} saturates at a constant value (*i.e.* it no longer increases with increasing V_{DS} .) Figure 2 shows the I - V operating curves for a typical n-channel enhancement-mode Field Effect Transistor (FET). As can be seen in the figure, for each value of V_{GS} there is a unique curve of I_{DS} vs. V_{DS} .

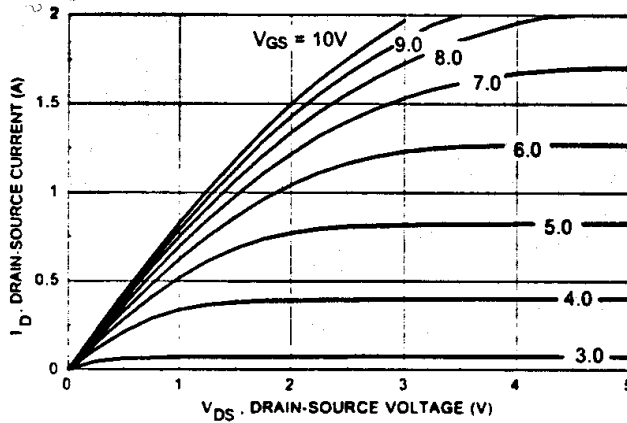


Figure 2 Current I_{DS} flowing through the drain to source of an n-channel MOSFET versus the voltage V_{DS} across drain to source, parameterized by the voltage V_{GS} applied across the gate to source.

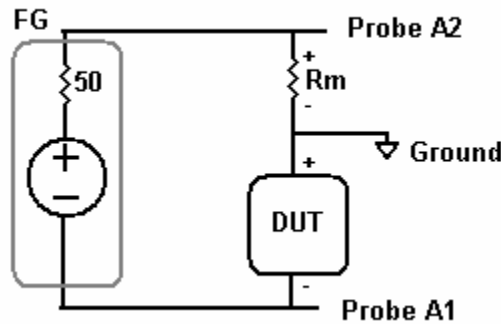


Figure 3 Curve-tracer circuit

Hands On

1. Build the curve-tracer circuit. Use $R_M = 1k$. Apply a 10 VPP sine wave at 100 Hz.
2. Invert Channel A1 by pressing the A1 button in the analog section and select

Invert On. Put the scope in the XY mode: press the Main/Delayed button, followed by the XY softkey. Use the analog position knobs to put the origin (0V, 0A) of the I-V plot in a convenient location.

3. Insert a resistor as the DUT, and measure the resistance R_{DUT} using the cursors. Keep in mind that the Y-axis is related to the device current: $V_{A2} = I R_M$.
4. Next, try using an LED as the DUT. Place the cathode (-) at ground. Adjust the analog volts/div until the curve fills the screen as much as possible.
5. Sketch the curve, making sure to indicate the voltage scales on each axis. Note the approximate voltage where the diode “turns on.”
6. Reverse the LED and sketch the curve again.
7. Insert a $0.1 \mu\text{F}$ capacitor as the DUT. Vary the signal frequency to see what happens. Why does the capacitor produce this peculiar curve? Sketch the curve at a frequency and scaling that produces an open ellipse.
8. Next we'll make some changes to the circuit to allow us to measure n-channel MOSFET curves. Remember that a transistor is a three-terminal device, and that an n-channel MOSFET requires a positive voltage across the gate to source to allow a current to flow from the drain to the source. You will provide this voltage with the DC power supply with the DC power supply.

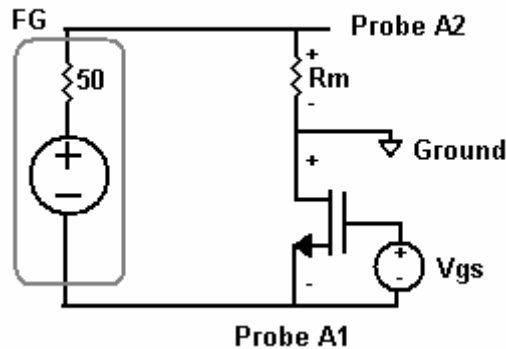


Figure 4 MOSFET curve tracer

1. Change R_M to 51 ohms. Set the 6V power supply to 0V initially, and connect it to the gate and source of the MOSFET as shown in the schematic. Note the pin designations D, G, S.
2. You will need to incrementally raise the voltage on the gate to see the I-V curve change. Use the position knobs to move the origin to the lower left corner of the scope screen. Sketch the family of curves for $V_{GS} = 2.5, 2.6, 2.7 \dots 3.1\text{V}$. Be sure to clearly mark each curve with its corresponding V_{GS} . Use the Auto-Store button to store I-V curves on the screen.